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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# PMBFJ108; PMBFJ109; PMBFJ110

# N-channel junction FETs

Rev. 4 — 20 September 2011

**Product data sheet** 

### 1. Product profile

### 1.1 General description

Symmetrical N-channel junction FETs in a SOT23 package.

#### 1.2 Features and benefits

- High-speed switching
- Interchangeability of drain and source connections
- Low  $R_{DSon}$  at zero gate voltage (< 8  $\Omega$  for PMBFJ108).

### 1.3 Applications

- Analog switches
- Choppers and commutators
- Audio amplifiers.

### 2. Pinning information

Table 1. Pinning

Pin	Description[1]	Simplified outline Symbol
1	drain	□3
2	source	
3	gate	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

<sup>[1]</sup> Drain and source are interchangeable.



### 3. Ordering information

Table 2. Ordering information

Type number	Package	Package		
	Name	Description	Version	
PMBFJ108	-	plastic surface mounted package; 3 leads	SOT23	
PMBFJ109				
PMBFJ110				

### 4. Marking

Table 3. Marking

•	
Type number	Marking code <sup>[1]</sup>
PMBFJ108	38*
PMBFJ109	39*
PMBFJ110	40*

<sup>[1] \* =</sup> p: Made in Hong Kong

### 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage (DC)		-	±25	V
$V_{GSO}$	gate-source voltage		-	-25	V
$V_{GDO}$	gate-drain voltage		-	-25	V
I <sub>G</sub>	forward gate current (DC)		-	50	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[1] -	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C

<sup>[1]</sup> Mounted on an FR4 printed-circuit board.

### 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> 500	K/W

<sup>[1]</sup> Mounted on an FR4 printed-circuit board.

<sup>\* =</sup> t: Made in Malaysia

<sup>\* =</sup> W: Made in China

### 7. Static characteristics

#### Table 6. Static characteristics

 $T_i = 25 \, {}^{\circ}C.$ 

,						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{GSS}$	gate-source leakage current	$V_{GS} = -15 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	-3	nΑ
I <sub>DSX</sub>	drain-source cut-off current	$V_{GS} = -10 \text{ V}; V_{DS} = 5 \text{ V}$	-	-	3	nΑ
I <sub>DSS</sub>	drain-source leakage current					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	80	-	-	mA
	PMBFJ109	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	40	-	-	mA
	PMBFJ110	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	10	-	-	mA
V <sub>(BR)GSS</sub>	gate-source breakdown voltage	$I_G = -1 \mu A; V_{DS} = 0 V$	-	-	-25	V
$V_{GSoff}$	gate-source cut-off voltage					
	PMBFJ108	$I_D = 1 \mu A; V_{DS} = 5 V$	-10	-	-3	V
	PMBFJ109	$I_D = 1 \mu A; V_{DS} = 5 V$	-6	-	-2	V
	PMBFJ110	$I_D = 1 \mu A; V_{DS} = 5 V$	-4	-	-0.5	V
R <sub>DSon</sub>	drain-source on-state resistance					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	8	Ω
	PMBFJ109	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	12	Ω
	PMBFJ110	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	18	Ω

### 8. Dynamic characteristics

#### Table 7. Dynamic characteristics

 $T_i = 25$  °C unless otherwise specified.

Parameter	Conditions	Min	Тур	Max	Unit
input capacitance	$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$	-	15	30	рF
	$V_{DS} = 0 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$	-	50	85	рF
feedback capacitance	$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$	-	8	15	рF
g times (see Figure 2)					
delay time		<u>[1]</u> -	2	-	ns
turn-on time		<u>[1]</u> _	4	-	ns
storage time		<u>[1]</u> -	4	-	ns
turn-off time		[1] -	6	-	ns
	input capacitance  feedback capacitance  g times (see Figure 2)  delay time  turn-on time  storage time	input capacitance $\begin{aligned} &V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz} \\ &V_{DS} = 0 \text{ V; } V_{GS} = 0 \text{ V; } f = 1 \text{ MHz; } T_{amb} = 25 \text{ °C} \end{aligned}$ feedback capacitance $V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz}$ g times (see Figure 2) delay time turn-on time storage time	input capacitance $\begin{array}{c} V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz} \\ V_{DS} = 0 \text{ V; } V_{GS} = 0 \text{ V; } f = 1 \text{ MHz; } T_{amb} = 25 \text{ °C} \end{array} \\ = \begin{array}{c} feedback \text{ capacitance} \\ V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz} \end{array} \\ = \begin{array}{c} g \text{ times (see Figure 2)} \\ delay \text{ time} \\ turn-on \text{ time} \\ storage \text{ time} \\ \end{array} \\ \begin{array}{c} [1] \\ [1] \\ [1] \\ [1] \\ \end{array}$	input capacitance $\begin{array}{c} V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz} \\ V_{DS} = 0 \text{ V; } V_{GS} = 0 \text{ V; } f = 1 \text{ MHz; } T_{amb} = 25 \text{ °C} \\ \end{array} \begin{array}{c} -50 \\ 50 \\ \end{array}$ feedback capacitance $\begin{array}{c} V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz} \\ \end{array} \begin{array}{c} -8 \\ \end{array}$ 8 g times (see Figure 2) delay time $\begin{array}{c} 11 \\ 11 \\ -2 \\ \end{array}$ turn-on time $\begin{array}{c} 11 \\ 11 \\ -4 \\ \end{array}$ storage time	input capacitance $\frac{V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz}}{V_{DS} = 0 \text{ V; } V_{GS} = 0 \text{ V; } f = 1 \text{ MHz; } T_{amb} = 25 \text{ °C}} - 50 \text{ 85}}$ feedback capacitance $V_{DS} = 0 \text{ V; } V_{GS} = -10 \text{ V; } f = 1 \text{ MHz}} - 8 \text{ 15}$ g times (see Figure 2) delay time $\frac{11}{10} - 2 - \frac{11}{10} - 4 - \frac{11}{10} - 11$

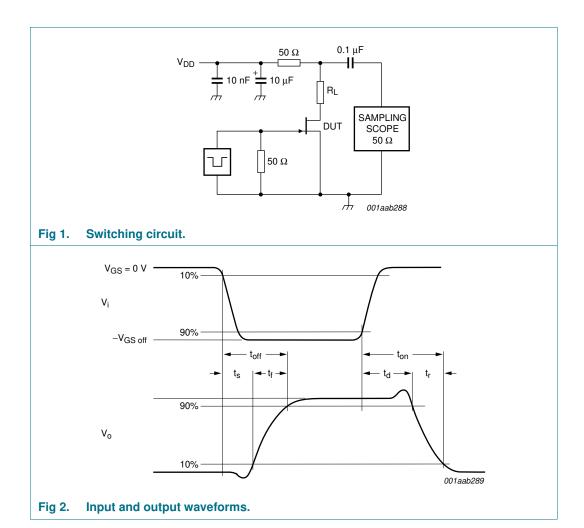
[1] Test conditions for switching times are as follows:

 $V_{DD}$  = 1.5 V,  $V_{GS}$  = 0 V to  $V_{GSoff}$  (all types);

 $V_{GSoff} = -12 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ108)};$ 

 $V_{GSoff} = -7 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ109)};$ 

 $V_{GSoff}$  = -5 V,  $R_L$  = 100  $\Omega$  (PMBFJ110).



### 9. Package outline

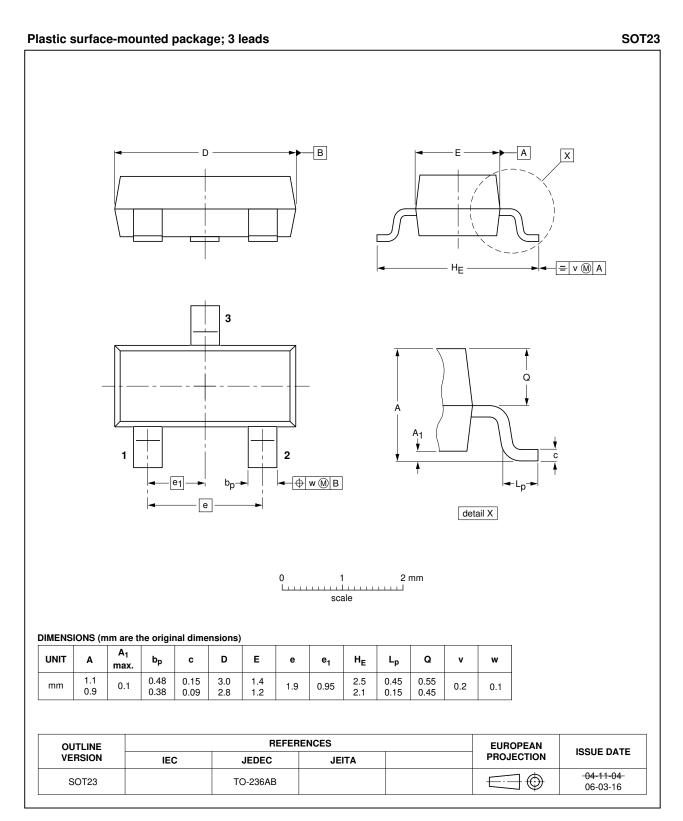


Fig 3. Package outline.

### 10. Revision history

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMBFJ108_109_110 v.4	20110920	Product data sheet	-	PMBFJ108_109_110 v.3
Modifications:	guidelines of Legal texts	of NXP Semiconductors.	ne new company r	comply with the new identity name where appropriate. atest version.
PMBFJ108_109_110 v.3 (9397 750 13401)	20040804	Product data sheet	-	PMBFJ108_109_110_CNV v.2
PMBFJ108_109_110_CNV v.2	19971201	Product specification	-	-

### 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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**N-channel junction FETs** 

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